

# On the Correlation between the Composition of Garnet Type Materials and their Photoluminescence Properties

A. Katelnikovas<sup>a,b</sup>, D. Uhlich<sup>a</sup>, H. Bettentrup<sup>a</sup>, J. Plewa<sup>a</sup>, A. Kareiva<sup>b</sup> and T. Jüstel<sup>a</sup>



<sup>a</sup>Department of Chemical Engineering, Münster University of Applied Sciences, Stegerwaldstr. 39, D-48565 Steinfurt, Germany  
<sup>b</sup>Department of General and Inorganic Chemistry, Vilnius University, Naugarduko 24, LT-03225 Vilnius, Lithuania



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## Introduction

Garnet is the common name of a group of cubic minerals belonging to the nesosilicates, which contain solely isolated tetrahedral  $[\text{SiO}_4]^{4-}$  units. The general formula of garnets is  $\text{C}_3\text{A}_2\text{D}_3\text{O}_{12}$ , which, in case of natural garnets, can be written as  $\text{C}_3\text{A}_2(\text{SiO}_4)_3$ , where  $\text{C} = \text{Fe}^{2+}, \text{Mg}^{2+}, \text{Ca}^{2+}$  and  $\text{A} = \text{Al}^{3+}, \text{Fe}^{3+}, \text{Cr}^{3+}$  and  $\text{V}^{3+}$ . In the general formula,  $\text{O}$  denotes oxygen and  $\text{C}, \text{A}, \text{D}$  symbolize cations occupying the dodecahedral, octahedral and tetrahedral sites, respectively. Artificial garnets according to the formula  $(\text{Y}_{1-x}\text{Lu}_x)_3(\text{Al}_{1-y}\text{Ga}_y)_5\text{O}_{12}$  are applied as hosts for laser gain media, scintillators, and LED phosphors.

In the present study, the luminescent properties of  $\text{Nd}^{3+}$ ,  $\text{Pr}^{3+}$  and  $\text{Ce}^{3+}$  doped garnet type host lattices, namely  $\text{Lu}_3(\text{Al}_{1-y}\text{Ga}_y)_5\text{O}_{12}$ ,  $(\text{Y}_{1-x}\text{Lu}_x)_3\text{Mg}_2\text{AlSi}_2\text{O}_{12}$  and  $(\text{Y}_{1-x}\text{Lu}_x)_3\text{Al}_3\text{MgSiO}_{12}$ , are discussed as a function of their composition.

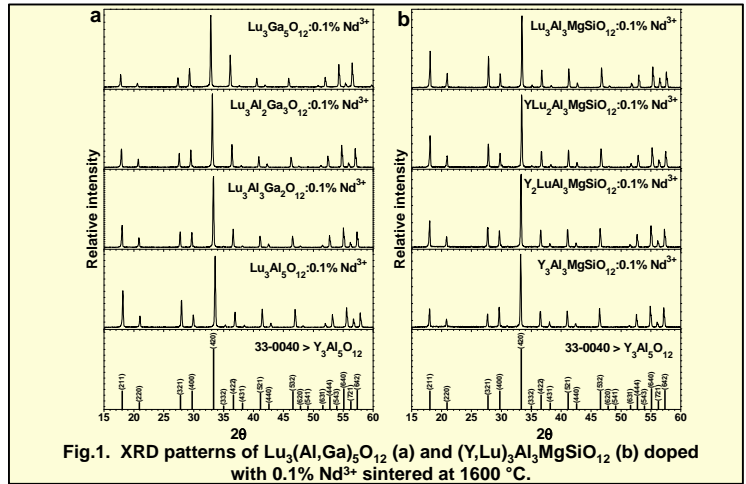


Fig.1. XRD patterns of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}$  (a) and  $(\text{Y,Lu})_3\text{Al}_3\text{MgSiO}_{12}$  (b) doped with 0.1%  $\text{Nd}^{3+}$  sintered at 1600 °C.

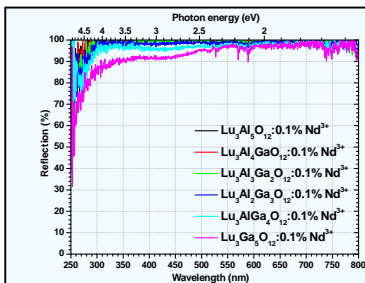


Fig. 2. Reflection spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:0.1\%\text{Nd}^{3+}$

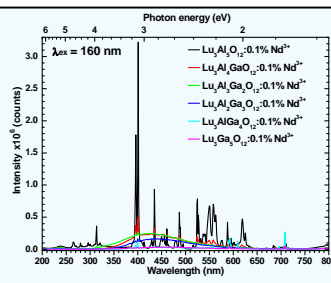


Fig. 3. Emission spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:0.1\%\text{Nd}^{3+}$

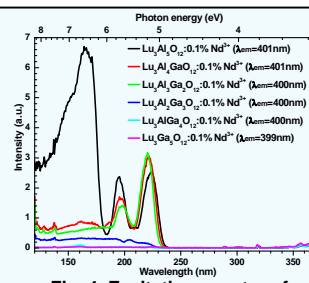


Fig. 4. Excitation spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:0.1\%\text{Nd}^{3+}$

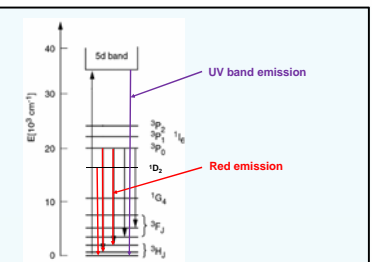


Fig. 5. Simplified Dieke Diagram of  $\text{Pr}^{3+}$  involving the lowest crystal-field component of the  $[\text{Xe}]4f^5d^1$  config.

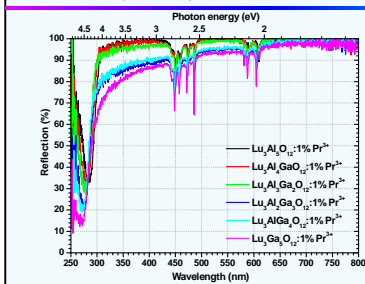


Fig. 6. Reflection spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:1\%\text{Pr}^{3+}$

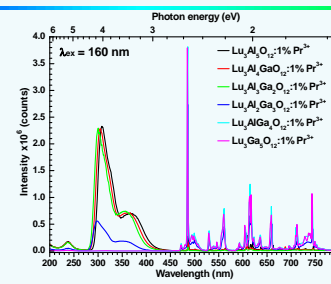


Fig. 7. Emission spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:1\%\text{Pr}^{3+}$

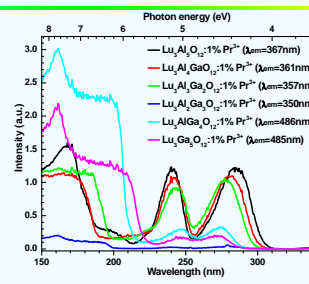


Fig. 8. Excitation spectra of  $\text{Lu}_3(\text{Al,Ga})_5\text{O}_{12}:1\%\text{Pr}^{3+}$

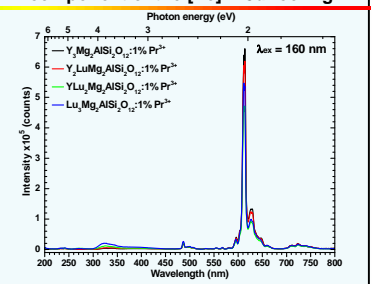


Fig. 9. Emission spectra of  $(\text{Y,Lu})_3\text{Mg}_2\text{AlSi}_2\text{O}_{12}:1\%\text{Pr}^{3+}$

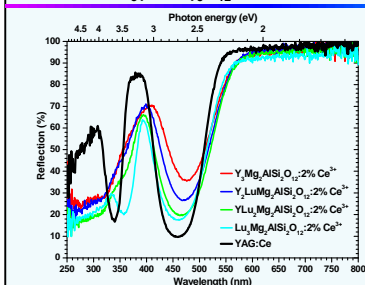


Fig. 10. Reflection spectra of  $(\text{Y,Lu})_3\text{Mg}_2\text{AlSi}_2\text{O}_{12}:2\%\text{Ce}^{3+}$

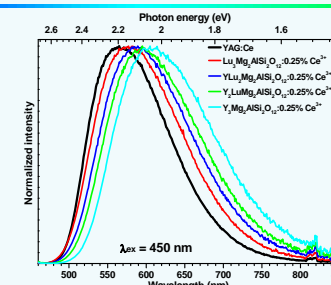


Fig. 11. Emission spectra of  $(\text{Y,Lu})_3\text{Mg}_2\text{AlSi}_2\text{O}_{12}:0.25\%\text{Ce}^{3+}$

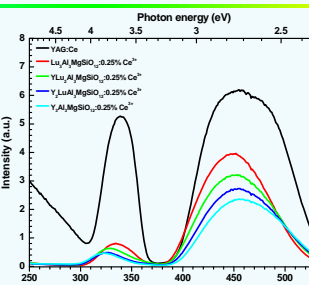


Fig. 12. Excitation spectra of  $(\text{Y,Lu})_3\text{Al}_3\text{MgSiO}_{12}:0.25\%\text{Ce}^{3+}$

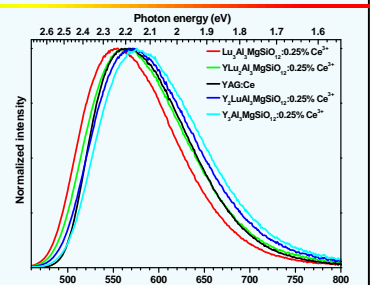


Fig. 13. Emission spectra of  $(\text{Y,Lu})_3\text{Al}_3\text{MgSiO}_{12}:0.25\%\text{Ce}^{3+}$

## Conclusions

In this work, we demonstrated that a modification of the LuAG host by Ga, Y, or Si and Mg results in strong changes with respect to the optical spectra of  $\text{Ce}^{3+}$ ,  $\text{Pr}^{3+}$ , or  $\text{Nd}^{3+}$  located onto the dodecahedral garnet sites.  $\text{Ce}^{3+}$  emits in LuAG:Ce at around 525 nm. Any replacement of Lu by Y or Al by Mg and Si, results in a red-shift. Even a 600 nm emitting garnet is feasible by using  $\text{Y}_3\text{Mg}_2\text{AlSi}_2\text{O}_{12}$  as a host.  $\text{Pr}^{3+}$  doped garnets show very peculiar spectra, due to presence of 4f-5d (UV range) and 4f-4f (visible range) transitions. The ratio of band to line emission can be easily tuned by the garnet composition. While LuAG:Pr mainly shows several 4f-5d emission bands in the UV range, in all Si/Mg comprising garnets the 4f-4f line transitions dominate the spectrum. The well known LuAG:Nd reveals intense visible emission lines upon 160 nm excitation. The replacement of  $\text{Al}^{3+}$  by  $\text{Ga}^{3+}$  results in a band gap shift from 180 to 215 nm. At the same time, the luminescence of  $\text{Nd}^{3+}$  in the visible range is completely quenched, which reveals that the ET from the host lattice excitons to the 4f-4f states of the dopant  $\text{Nd}^{3+}$  is mediated by the high lying 4f5d-levels at 195 and 220 nm.